

RJM0404JSC

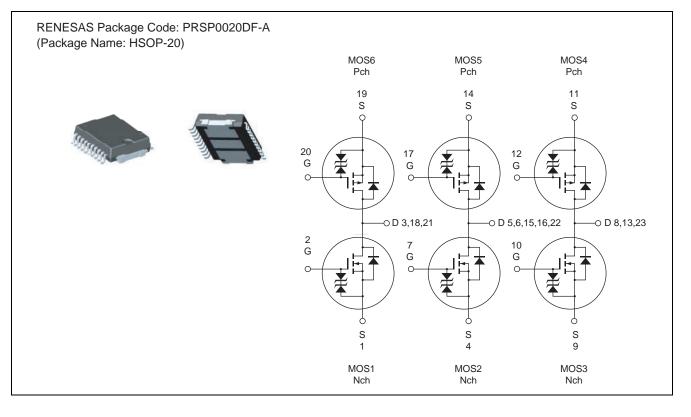
Silicon N/P Channel Power MOS FET (6 in 1 Type) High Speed Power Switching

R07DS0338EJ0500 Rev.5.00 May 11, 2011

Features

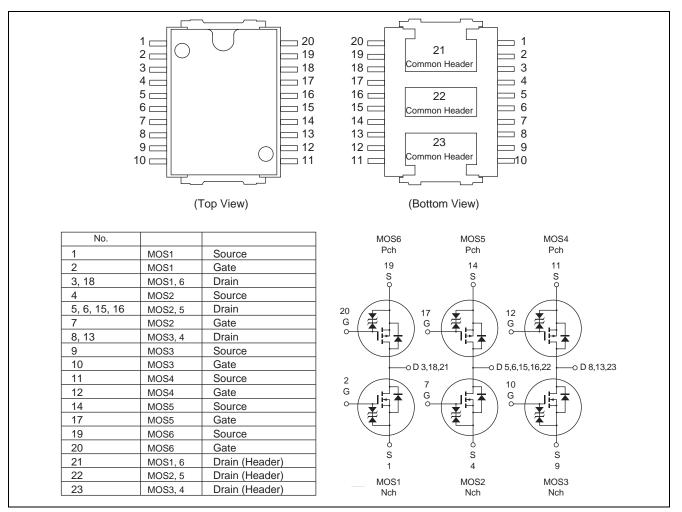
- For Automotive applications
- AEC-Q101 compliant
- N/P Channel MOS FET (6 in 1 Type). High density mounting
- Low on-resistance
- Capable of 4.5 V gate drive

Outline





Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

				(10 - 25 0)
Item	Symbol	Va	Unit	
	Symbol	MOS1, 2, 3 (Nch)	MOS4, 5, 6 (Pch)	Onit
Drain to source voltage	V _{DSS}	40	-40	V
Gate to source voltage	V _{GSS}	+20 /5	-20 / +5	V
Drain current	ID	20	-20	A
Drain peak current	I _D (pulse) Note1	80	-80	A
Avalanche current	I _{AP} Note3	20	-20	A
Avalanche energy	E _{AR} Note3	53	53	mJ
Channel dissipation	Pch Note2	54	54	W
Channel temperature	Tch Note4	175	175	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	°C

Notes: 1. $PW \le 10\mu s$ duty cycle $\le 1\%$

- 2. $Tc = 25^{\circ}C : 1$ Drive Operation.
- 3. Tch = 25°C, Rg \geq 50 Ω
- 4. AEC-Q101 compliant

Thermal Impedance Characteristics

• Channel to case thermal impedance θ ch-c: 2.78°C/W



Electrical Characteristics

• MOS1, MOS2, MOS3 (N Channel)

						(Ta = 25°C)
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage drain current	I _{DSS}	_	_	10	μΑ	$V_{DS} = 40 V, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	—	±10	μΑ	$V_{GS} = +20 / -5 V, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.0	—	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	17	21	mΩ	$I_D = 10 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$
resistance		_	24	34	mΩ	$I_D = 10 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note5}}$
Input capacitance	Ciss	_	1400	_	pF	$V_{DS} = 10V, V_{GS} = 0,$ f = 1 MHz
Output capacitance	Coss	_	230	_	pF	
Reverse transfer capacitance	Crss	_	100	_	pF	
Total gate charge	Qg	_	23		nC	$V_{DD} = 25 \text{ V}, V_{GS} = 10 \text{ V},$ $I_D = 20 \text{ A}$
Gate to source charge	Qgs	_	3		nC	
Gate to drain charge	Qgd	_	4		nC	
Turn-on delay time	t _{d(on)}	_	15		ns	$\label{eq:VGS} \begin{split} V_{GS} &= 10 \ V, \ I_D = 10 \ A, \\ V_{DD} &\cong 20 \ V, R_L = 2 \ \Omega, \\ R_G &= 4.7 \ \Omega \end{split}$
Rise time	tr	_	35		ns	
Turn-off delay time	t _{d(off)}	_	50		ns	
Fall time	t _f	_	8		ns	
Body-drain diode forward voltage	V _{DF}	_	0.92	1.2	V	$I_F = 20 \text{ A}, V_{GS} = 0^{Note5}$
Body-drain diode reverse recovery	t _{rr}		20	_	ns	$I_F = 20 \text{ A}, V_{GS} = 0$
time						di _F /dt = 50 A/µs

Note: 5. Pulse test

• MOS4, MOS5, MOS6 (P Channel)

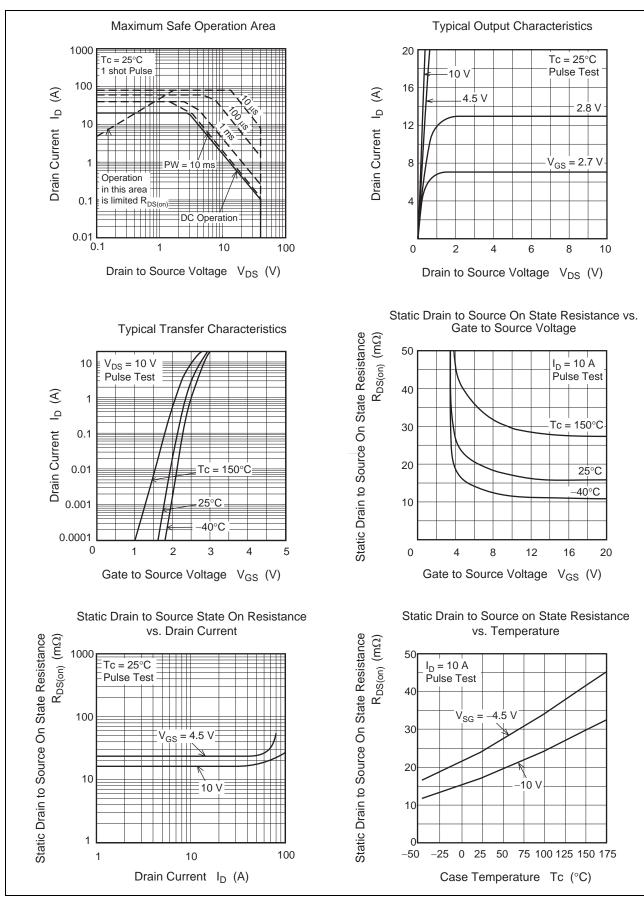
						(Ta = 25°C)
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage drain current	I _{DSS}	_	_	-10	μΑ	$V_{DS} = -40 V, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	—	±10	μΑ	$V_{GS} = -20 / +5 V, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	-1.0	_	-2.5	V	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	34	42	mΩ	$I_D = -10 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note6}}$
resistance		_	48	68	mΩ	$I_D = -10 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note6}}$
Input capacitance	Ciss	_	1500	—	pF	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0,$ f = 1 MHz
Output capacitance	Coss		230		pF	
Reverse transfer capacitance	Crss		140		pF	
Total gate charge	Qg		25		nC	$V_{DD} = -25 \text{ V}, V_{GS} = -10 \text{ V},$ $I_D = -20 \text{ A}$
Gate to source charge	Qgs		5		nC	
Gate to drain charge	Qgd		4		nC	
Turn-on delay time	t _{d(on)}		30		ns	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -10 \text{ A},$
Rise time	tr		55		ns	
Turn-off delay time	t _{d(off)}		50		ns	
Fall time	t _f		20		ns	
Body-drain diode forward voltage	V _{DF}		-0.97	-1.26	V	$I_F = -20 \text{ A}, V_{GS} = 0^{\text{Note6}}$
Body-drain diode reverse recovery	t _{rr}	_	30	—	ns	$I_F = -20 \text{ A}, V_{GS} = 0$
time						di _F /dt = 50 A/µs

Note: 6. Pulse test



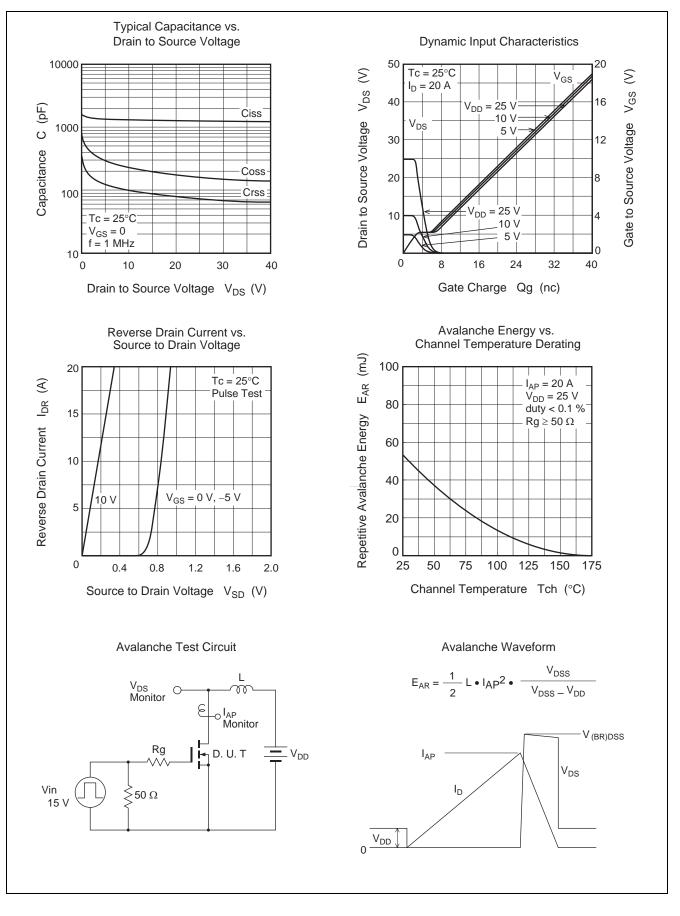
Main Characteristics

• MOS1, 2, 3 (Nch)



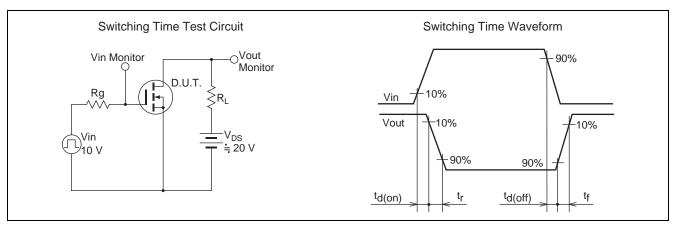


• MOS1, 2, 3(Nch)



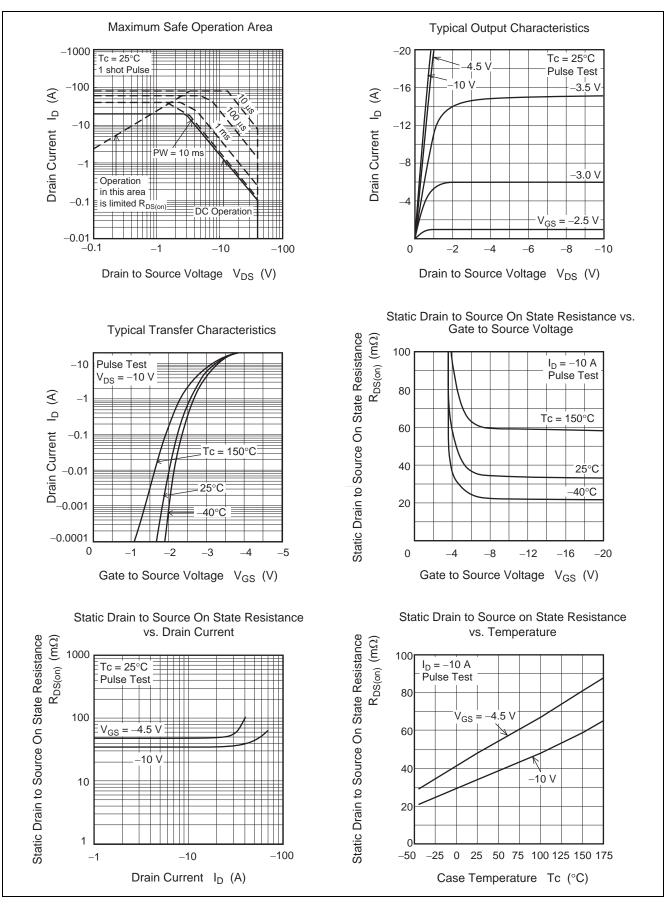


• MOS1, 2, 3 (Nch)



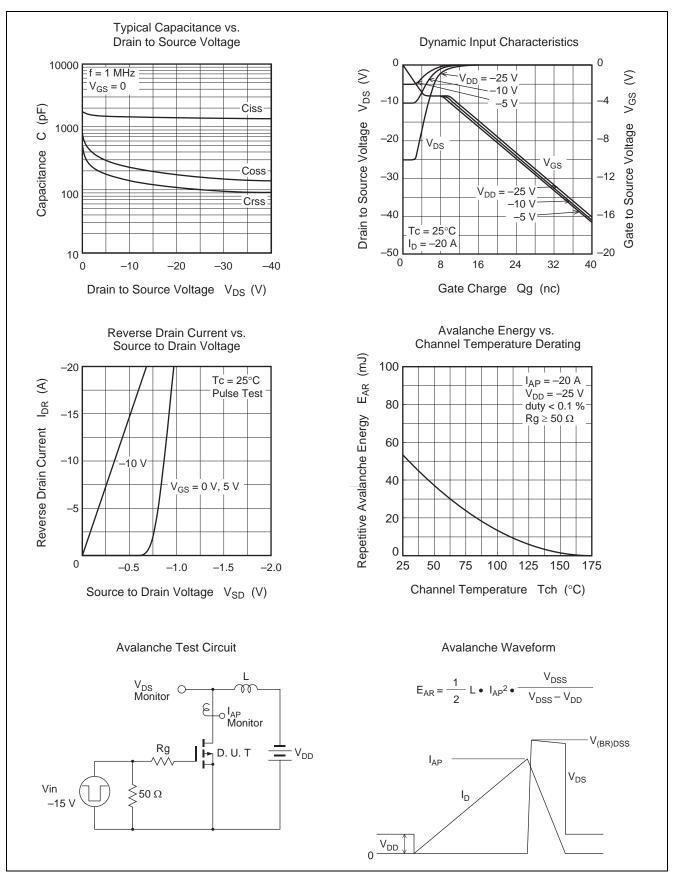


• MOS4, 5, 6 (Pch)



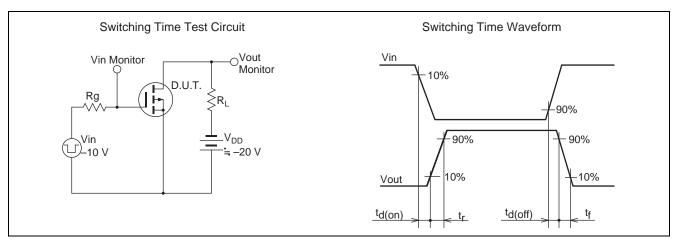


• MOS4, 5, 6 (Pch)



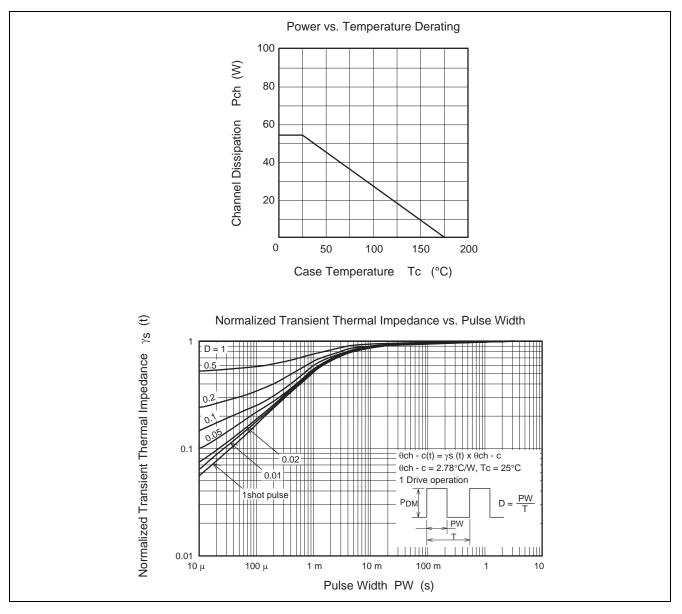


• MOS4, 5, 6 (Pch)



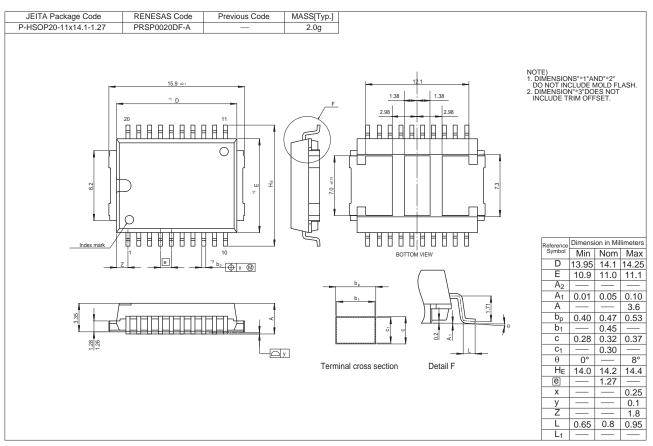


• Common





Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJM0404JSC-00-12	700 pcs	Tray



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